

M.2 (P110) 4TS2-P

HIGHLIGHT FEATURES

- PCIe Gen 4 x4, NVMe 1.4
- PLP (iCell) technology for power loss protection
- Stable sustained performance
- LDPC ECC engine supported
- Dynamic Thermal Management

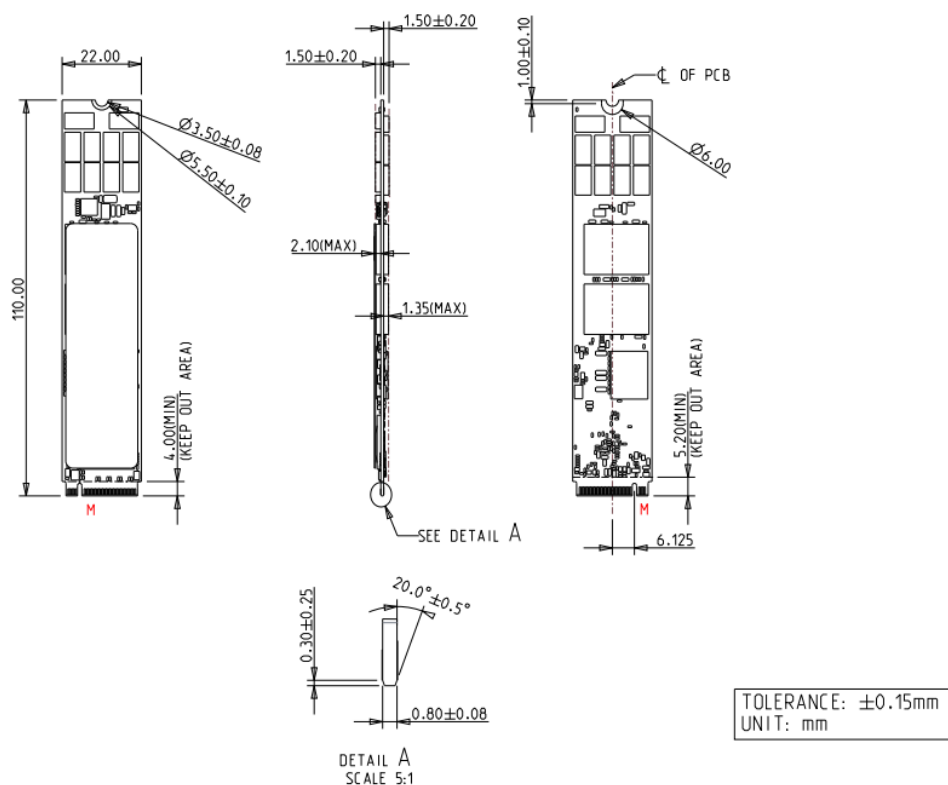


SPECIFICATIONS

Model Name	M.2 (P110) 4TS2-P
Flash Type	3D TLC
Interface	PCIe Gen 4 x4
Form Factor	M.2 22110 M Key
Capacity	240GB ~ 1.92TB
Sequential R / W (MB/sec, max.)	6,600 / 1,550
P/E Cycle	7,000
TBW (Max.)	3,187 (DWPD=1)
Storage Temperature	-40°C ~ 85°C
Max. Power Consumption	5.6W
Max. Channels	8
External DRAM Buffer	Y
H/W Write Protect	N
S.M.A.R.T.	Y
AES	Y (Optional)
TCG Opal	Y (Optional)
Dimension (W x L x H/mm)	Pure M.2 : 22.0 x 110.0 x 2.87 S/T with heat-spreading copper layer : 22.0 x 110.0 x 3.3
Vibration	20G@[7 ~ 2000Hz]
Shock	1500G@0.5ms
MTBF	>3 million hours
Warranty	5 Years

DIAGRAM

ST



ORDER INFO.

Operating Temperature	Standard Grade (0°C ~ 70°C)
240GB	DSM21-240DP1NC#Q%P
480GB	DSM21-480DP1NC#E%P
960GB	DSM21-960DP1NCB&%P
1.92TB	DSM21-1T9DP1NCBE%P

Operation temperature based on temperature obtained from S.M.A.R.T.

For TCG Opal function, the PN Code 10th ~12th will be DP2.

#: BOM revision

&: Q=4-channel / E=8-channel.

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